



Gas Sensor based on WO₃ (Tungsten Trioxide) nanoparticles



Main Features

- High sensitivity and selectivity
- Low power consumption
- Detection of wide variety of gas (NH₃, C₂H₅OH, CO, SO₂,...)
- Easy-to-use
- Low cost
- Temperature sensor included
- Heater included
- Small size

Description

This gas sensor is developed at Atelier Interuniversitaire de Micro-nano Electronique (AIME) as part of the UF Smart Device module in the PTP Innovative Smart System curriculum. The gas sensor is based on a type of metal oxide semiconductor, which is tungsten trioxide (WO_3) nanoparticles. The sensing element used for gas measurement is composed of interdigitated combs of silicon substrate with a thin tungsten trioxide nanoparticles (WO_3) deposit. Each sensor consists of two such sensing elements. The gas sensor also has an aluminium resistor that acts as a temperature sensor and an integrated heater formed on a wide N-doped polysilicon layer which allows heating of the sensor up to 300°C. When molecules of detectable gas come into contact with the nanoparticles, the resistances vary according to the concentration and type of gas. Therefore, an external electronic measuring device may determine the nature and concentration of gas based on the variation of resistances. With the help of the integrated heater and the integrated temperature sensor, sensitivity and selectivity can be configured. Thanks to these, this gas sensor module is highly reliable with high sensitivity and selectivity.





Specifications

Туре	Nanoparticle based sensor		
Materials	 Silicon N-doped poly-silicon (heater) Aluminum (temperature measurement) Nanoparticles of tungsten trioxide (WO3) 		
Power supply requirement	Active sensor		
Gas measurement	Resistive measure		
Temperature measurement	Resistive measure		
Nature of output signals	Analog		
Detectable gas	 Nitrogen dioxide (NO2) Ammonia (NH3) Carbon monoxide (CO) Hydrogen sulfide (SO2) Dihydrogen (H2) Methane (CH4) Alcohols (-OH)(ethanol C2H5OH) 		
Packaging	10-Lead TO-5 metal		
Diameter	9.5mm		
Mounting	Through hole fixed		
Time response	Ethanol <30sAmmonia <15s		

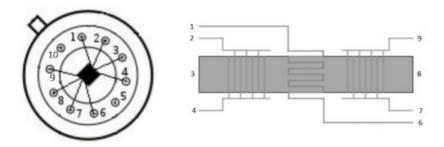
Standard use condition

	Unit	Typical value
Diameter ?	°C	20±5
Mounting ?	%	60±5
Time response ?	%N2/O2	80/20

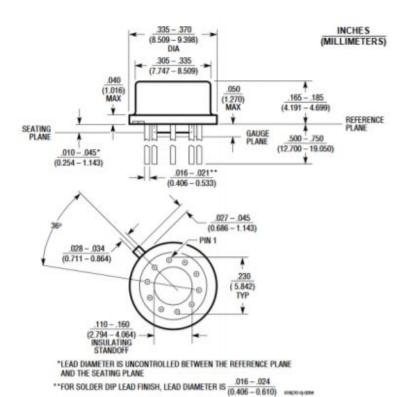




Pin Mapping & Usage



Pin number	Usage		
1/6	Temperature sensor (Aluminium resistor)		
2/4	Gas sensor (WO3 nanoparticles integrated on aluminium interdigital combs)		
3/8	Heater resistor (Polysilicon resistor)		
7/9	Gas sensor (WO3 nanoparticles integrated on aluminium interdigital combs)		
5/10	Not connected		







Ambient Temperature Characteristics

Component	Material	Resistance (Ω)	Parallel Experiments Resistance (Ω)		
Sensor Resistor	Aluminium	60	[63, 81]		
Heating Resistor	polySilicium	71	[65, 100]		

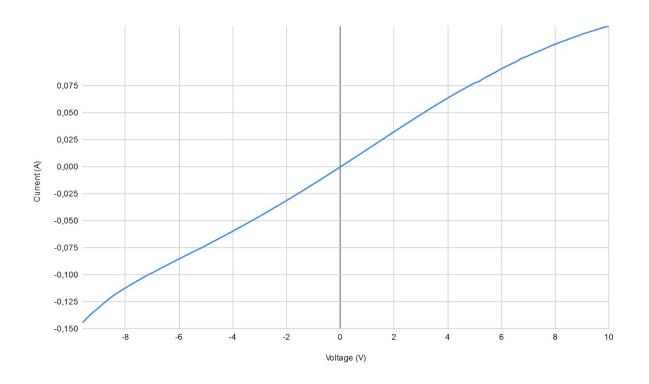


Figure 4: Aluminium Sensor Resistor Current/Voltage measurements





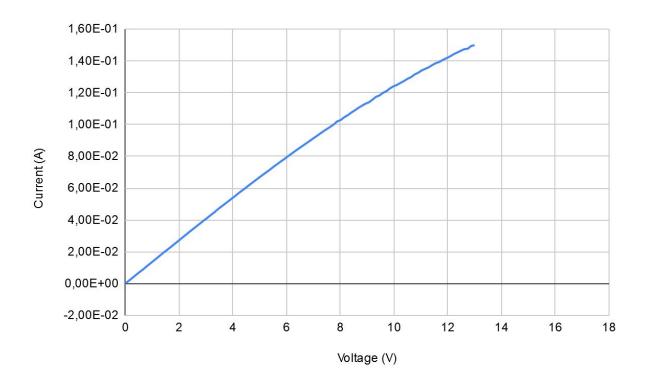


Figure 5: polySilicium Heating Resistor Current/Voltage measurements





Characteristics under gas exposure at certains temperatures

The characterization of the gas sensor has been performed around multiple temperatures, following a specific gas exposure procedure.

Dry Air - 2 mins Ethanol - 2 mins Dry Air - 2 mins Ethanol - 2 mins Dry Air - 2 mins NH₃ - 2 mins Dry Air - 2 mins

 NH_3 - 2 mins Dry Air - 2 mins

Temperature	ΔR/R0 N ₂ O ₂	Variation time N ₂ O ₂	ΔR/R0 CH ₃ CH ₂ O H (MΩ)	Variation time CH ₃ CH ₂ OH	$\Delta R/R0$ NH_3 $(M\Omega)$	Variation time NH ₃
300°C	+66%	50,35 s	-38%	29,83 s	-44%	22,94 s

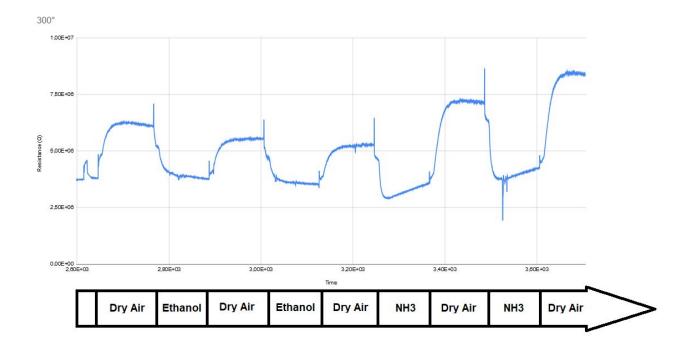


Figure 6: Resistor Variation over time under Gases exposures at 300°C





Parallel measurements

Temperature	ΔR/R0 N ₂ O ₂	Variatio n time N ₂ O ₂	ΔR/R0 CH ₃ CH ₂ O H (MΩ)	Variation time CH ₃ CH ₂ OH	Δ R/R0 NH ₃ (M Ω)	Variation time NH ₃
250°C	57%	100 s	-27%	25 s	-75%	6 s
227°C	203,7%	32 s	-	-	141,7%	25s
215°C	40,8%	39,3 s	-32,2%	80,4 s	-71,7%	99,5 s

Sensor exploitation

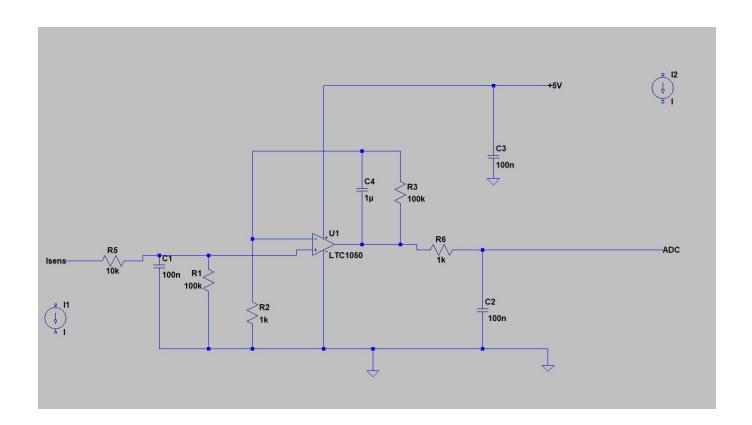


Figure 7: Electrical Diagram of a sensor application